## NSN 5961-00-767-9412

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-767-9412 **Inclosure Material:** Glass **Overall Length:** 0.080 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.085 inches **End Application:** Model no. E58 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 9.1 regulator voltage **Current Rating Per Characteristic:** 75.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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